



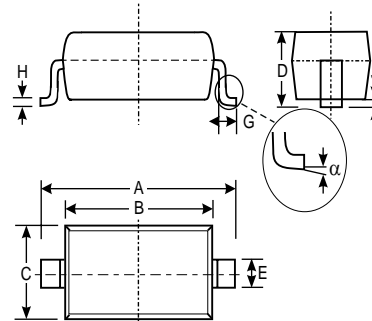
WEE Technology Company Limited

Silicon Planar Zener Diodes

BZT52C2V4 - BZT52C39

Features

- Planar Die Construction
- 500mW Power Dissipation on Ceramic PCB
- General Purpose, Medium Current
- Ideally Suited for Automated Assembly Processes



| SOD-123 | | |
|----------------------|--------------|------|
| Dim | Min | Max |
| A | 3.55 | 3.85 |
| B | 2.55 | 2.85 |
| C | 1.40 | 1.70 |
| D | — | 1.35 |
| E | 0.55 Typical | |
| G | 0.25 | — |
| H | 0.11 Typical | |
| J | — | 0.10 |
| α | 0° | 8° |
| All Dimensions in mm | | |

Mechanical Data

- Case: SOD-123, Plastic
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Marking: See Below
- Weight: 0.01 grams (approx.)
- Ordering Information: See Page 4

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|--|-----------------|-------------|--------------------|
| Forward Voltage (Note 2) @ $I_F = 10\text{mA}$ | V_F | 0.9 | V |
| Power Dissipation (Note 1) | P_d | 500 | mW |
| Thermal Resistance, Junction to Ambient Air (Note 1) | $R_{\theta JA}$ | 305 | $^\circ\text{C/W}$ |
| Operating and Storage Temperature Range | T_j, T_{STG} | -65 to +150 | $^\circ\text{C}$ |

- Notes:
1. Device mounted on ceramic PCB; 7.6mm x 9.4mm x 0.87mm with pad areas 25mm².
 2. Short duration test pulse used to minimize self-heating effect.



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Electrical Characteristics @ T_A = 25°C unless otherwise specified

| Type Number | Marking Code | Zener Voltage Range (Note 2) | | | | Maximum Zener Impedance (Note 3) | | | Maximum Reverse Current (Note 2) | | Typical Temperature Coefficient @ I _{ZTC} mV/°C | | Test Current I _{ZTC} mA |
|-------------|--------------|----------------------------------|---------|---------|-----------------|-----------------------------------|-----------------------------------|-----------------|----------------------------------|------------------|--|------|----------------------------------|
| | | V _Z @ I _{ZT} | | | I _{ZT} | Z _{KT} @ I _{ZT} | Z _{KK} @ I _{ZK} | I _{ZK} | I _R | @ V _R | Min | Max | |
| | | Nom (V) | Min (V) | Max (V) | mA | Ω | mA | uA | V | | | | |
| BZT52C2V4 | WX | 2.4 | 2.2 | 2.6 | 5 | 100 | 600 | 1.0 | 50 | 1.0 | -3.5 | 0 | 5 |
| BZT52C2V7 | W1 | 2.7 | 2.5 | 2.9 | 5 | 100 | 600 | 1.0 | 20 | 1.0 | -3.5 | 0 | 5 |
| BZT52C3V0 | W2 | 3.0 | 2.8 | 3.2 | 5 | 95 | 600 | 1.0 | 10 | 1.0 | -3.5 | 0 | 5 |
| BZT52C3V3 | W3 | 3.3 | 3.1 | 3.5 | 5 | 95 | 600 | 1.0 | 5.0 | 1.0 | -3.5 | 0 | 5 |
| BZT52C3V6 | W4 | 3.6 | 3.4 | 3.8 | 5 | 90 | 600 | 1.0 | 5.0 | 1.0 | -3.5 | 0 | 5 |
| BZT52C3V9 | W5 | 3.9 | 3.7 | 4.1 | 5 | 90 | 600 | 1.0 | 3.0 | 1.0 | -3.5 | 0 | 5 |
| BZT52C4V3 | W6 | 4.3 | 4.0 | 4.6 | 5 | 90 | 600 | 1.0 | 3.0 | 1.0 | -3.5 | 0 | 5 |
| BZT52C4V7 | W7 | 4.7 | 4.4 | 5.0 | 5 | 80 | 500 | 1.0 | 3.0 | 2.0 | -3.5 | 0.2 | 5 |
| BZT52C5V1 | W8 | 5.1 | 4.8 | 5.4 | 5 | 60 | 480 | 1.0 | 2.0 | 2.0 | -2.7 | 1.2 | 5 |
| BZT52C5V6 | W9 | 5.6 | 5.2 | 6.0 | 5 | 40 | 400 | 1.0 | 1.0 | 2.0 | -2 | 2.5 | 5 |
| BZT52C6V2 | WA | 6.2 | 5.8 | 6.6 | 5 | 10 | 150 | 1.0 | 3.0 | 4.0 | 0.4 | 3.7 | 5 |
| BZT52C6V8 | WB | 6.8 | 6.4 | 7.2 | 5 | 15 | 80 | 1.0 | 2.0 | 4.0 | 1.2 | 4.5 | 5 |
| BZT52C7V5 | WC | 7.5 | 7.0 | 7.9 | 5 | 15 | 80 | 1.0 | 1.0 | 5.0 | 2.5 | 5.3 | 5 |
| BZT52C8V2 | WD | 8.2 | 7.7 | 8.7 | 5 | 15 | 80 | 1.0 | 0.7 | 5.0 | 3.2 | 6.2 | 5 |
| BZT52C9V1 | WE | 9.1 | 8.5 | 9.6 | 5 | 15 | 100 | 1.0 | 0.5 | 6.0 | 3.8 | 7.0 | 5 |
| BZT52C10 | WF | 10 | 9.4 | 10.6 | 5 | 20 | 150 | 1.0 | 0.2 | 7.0 | 4.5 | 8.0 | 5 |
| BZT52C11 | WG | 11 | 10.4 | 11.6 | 5 | 20 | 150 | 1.0 | 0.1 | 8.0 | 5.4 | 9.0 | 5 |
| BZT52C12 | WH | 12 | 11.4 | 12.7 | 5 | 25 | 150 | 1.0 | 0.1 | 8.0 | 6.0 | 10.0 | 5 |
| BZT52C13 | WI | 13 | 12.4 | 14.1 | 5 | 30 | 170 | 1.0 | 0.1 | 8.0 | 7.0 | 11.0 | 5 |
| BZT52C15 | WJ | 15 | 13.8 | 15.6 | 5 | 30 | 200 | 1.0 | 0.1 | 10.5 | 9.2 | 13.0 | 5 |
| BZT52C16 | WK | 16 | 15.3 | 17.1 | 5 | 40 | 200 | 1.0 | 0.1 | 11.2 | 10.4 | 14.0 | 5 |
| BZT52C18 | WL | 18 | 16.8 | 19.1 | 5 | 45 | 225 | 1.0 | 0.1 | 12.6 | 12.4 | 16.0 | 5 |
| BZT52C20 | WM | 20 | 18.8 | 21.2 | 5 | 55 | 225 | 1.0 | 0.1 | 14.0 | 14.4 | 18.0 | 5 |
| BZT52C22 | WN | 22 | 20.8 | 23.3 | 5 | 55 | 250 | 1.0 | 0.1 | 15.4 | 16.4 | 20.0 | 5 |
| BZT52C24 | WO | 24 | 22.8 | 25.6 | 5 | 70 | 250 | 1.0 | 0.1 | 16.8 | 18.4 | 22.0 | 5 |
| BZT52C27 | WP | 27 | 25.1 | 28.9 | 2 | 80 | 300 | 0.5 | 0.1 | 18.9 | 21.4 | 25.3 | 2 |
| BZT52C30 | WQ | 30 | 28.0 | 32.0 | 2 | 80 | 300 | 0.5 | 0.1 | 21.0 | 24.4 | 29.4 | 2 |
| BZT52C33 | WR | 33 | 31.0 | 35.0 | 2 | 80 | 325 | 0.5 | 0.1 | 23.1 | 27.4 | 33.4 | 2 |
| BZT52C36 | WS | 36 | 34.0 | 38.0 | 2 | 90 | 350 | 0.5 | 0.1 | 25.2 | 30.4 | 37.4 | 2 |
| BZT52C39 | WT | 39 | 37.0 | 41.0 | 2 | 130 | 350 | 0.5 | 0.1 | 27.3 | 33.4 | 41.2 | 2 |

- Notes:
1. Device mounted on ceramic PCB; 7.6mm x 9.4mm x 0.87mm with pad areas 25mm².
 2. Short duration test pulse used to minimize self-heating effect.
 3. f = 1kHz.



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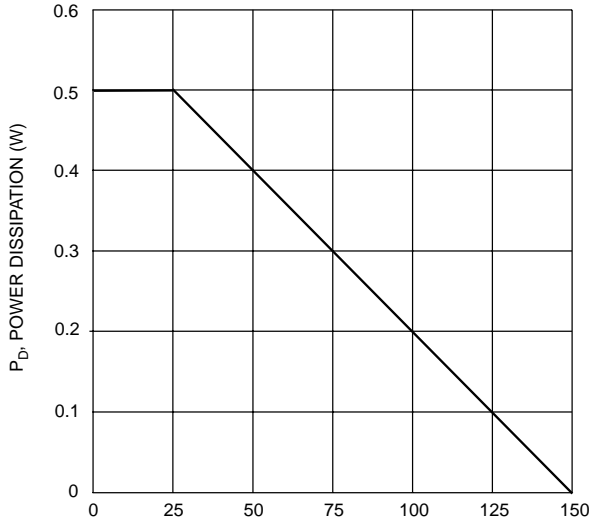


Fig. 1 Power Dissipation vs Ambient Temperature

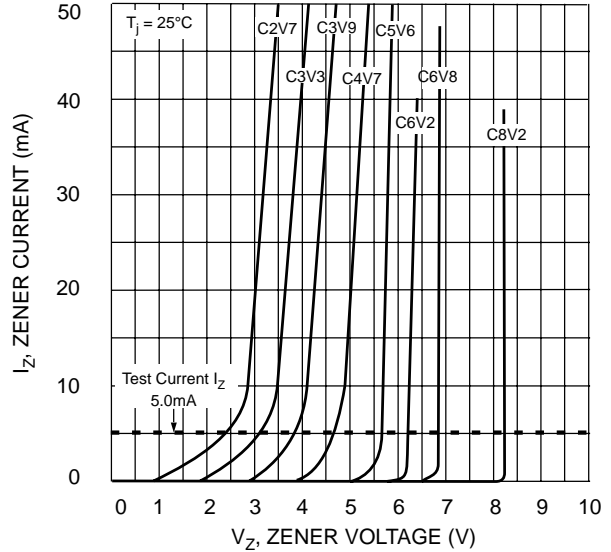


Fig. 2 Zener Breakdown Characteristics

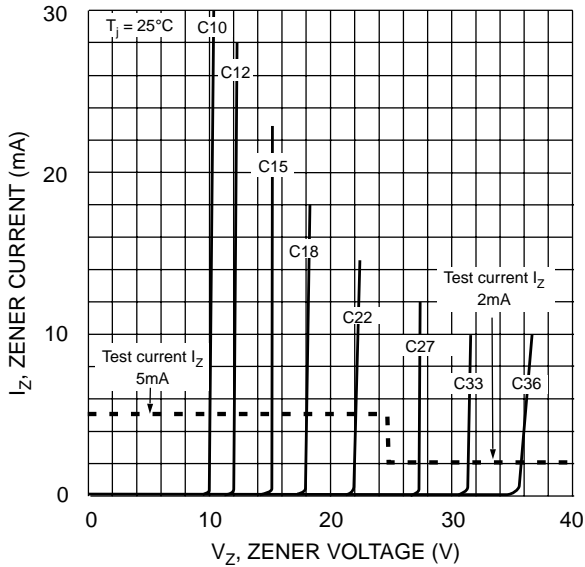


Fig. 3 Zener Breakdown Characteristics

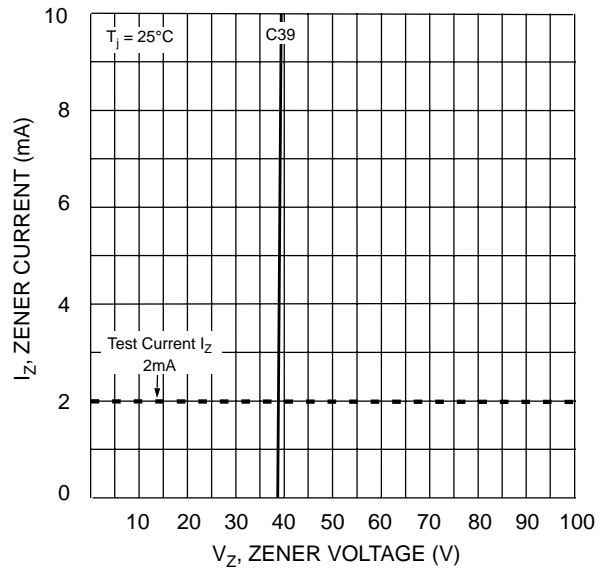


Fig. 4 Zener Breakdown Characteristics

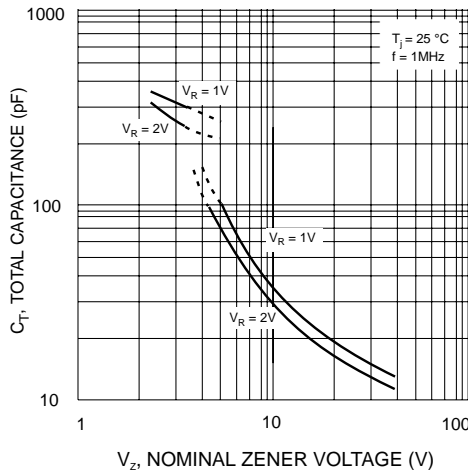


Fig. 5 Total Capacitance vs Nominal Zener Voltage

Note: Specifications are subject to change without notice. For more detail and update, please visit our website.